

#### **40V PNP LOW SATURATION TRANSISTOR IN SOT323**

#### **Features**

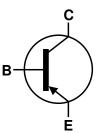
- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -1A Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -500 \text{mV}$  @  $I_C = -1 \text{A}$
- Ultra-Small Surface Mount Package
- Complementary NPN Type: DSS4140U
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

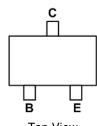
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated leads. Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight: 0.006 grams (Approximate)







Device Symbol



Top View Pin-Out

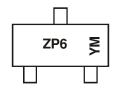
### **Ordering Information** (Note 4)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
DSS5140U-7	AEC-Q101	ZP6	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



ZP6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Year	2010	) 2	2011	2012	2013	2014	2015	2010	6 20	17 2	2018	2019	2020
Code	Х		Υ	Z	Α	В	С	D	E	Ξ	F	G	Н
Month	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	)	1	2	3	4	5	6	7	8	9	0	N	D



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current - Continuous	Ic	-1	Α
Peak Pulse Collector Current	I <sub>CM</sub>	-2	Α
Peak Base Current	I <sub>BM</sub>	-1	Α

# Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	400	mW	
Power Dissipation	(Note 6)	P <sub>D</sub>	500	IIIVV	
Thermal Decistores, Junction to Ambient	(Note 5)	0	313	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	250	- C/VV	
Thermal Resistance, Junction to Leads	$R_{ hetaJL}$	350	°C/W		
Operating and Storage Temperature Range	$T_{J}, T_{STG}$	-55 to +150	°C		

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	٧	С

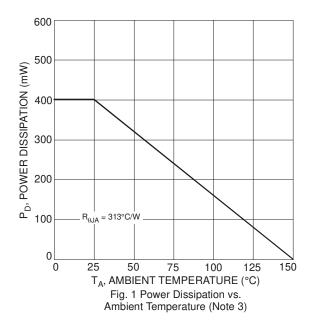
Notes:

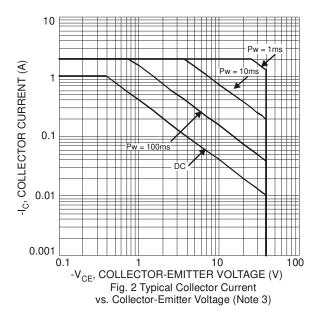
- 5. For a device mounted with collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as Note 5, except the collector lead is on a 25mm x 25mm 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the leads).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

October 2014



#### **Thermal Characteristics and Derating Information**





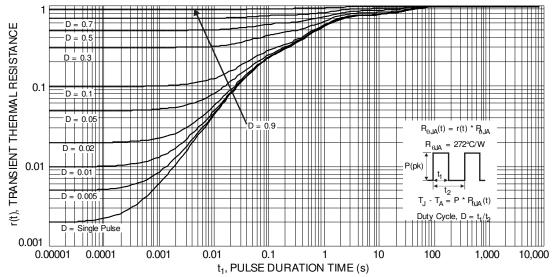


Fig. 3 Transient Thermal Response (Note 3)



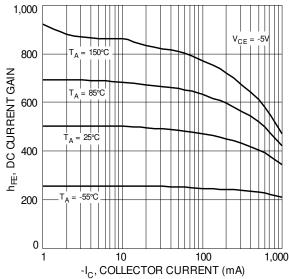
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

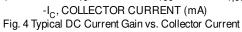
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	_	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-40	_	_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	_	_	٧	$I_E = -100 \mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	_	-100 -50	nA μA	$V_{CB} = -40V, I_{E} = 0$ $V_{CB} = -40V, I_{E} = 0, T_{J} = +150^{\circ}C$
Collector Cutoff Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CE</sub> = -40V, V <sub>BE</sub> = 0
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	-100	nA	$V_{EB} = -5V, I_{C} = 0$
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h <sub>FE</sub>	300 300 250 160		800 —	_	$V_{CE} = -5V$ , $I_{C} = -1mA$ $V_{CE} = -5V$ , $I_{C} = -100mA$ $V_{CE} = -5V$ , $I_{C} = -500mA$ $V_{CE} = -5V$ , $I_{C} = 1A$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>			-200 -250 -500	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -1mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Collector-Emitter Saturation Resistance	R <sub>CE(SAT)</sub>	_	_	500	mΩ	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>		_	-1.1	٧	$I_C = -1A$ , $I_B = -50mA$
Base-Emitter Turn On Voltage	V <sub>BE(ON)</sub>		_	-1	V	$V_{CE} = -5V, I_{C} = -1A$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>		13		pF	$V_{CB} = -10V, f = 1.0MHz$
Current Gain-Bandwidth Product	$f_T$	150	—	_	MHz	$V_{CE} = -10V$ , $I_{C} = -50mA$ , $f = 100MHz$
SWITCHING CHARACTERISTICS						
Turn-On Time	t <sub>on</sub>	_	60		ns	
Delay Time	t <sub>d</sub>	_	25	_	ns	
Rise Time	t <sub>r</sub>		35		ns	V <sub>CC</sub> = -10V
Turn-Off Time	t <sub>off</sub>		250	_	ns	$I_C = -0.5A$ , $I_{B1} = -I_{B2} = -25mA$
Storage Time	ts		220	_	ns	
Fall Time	t <sub>f</sub>	_	30	_	ns	

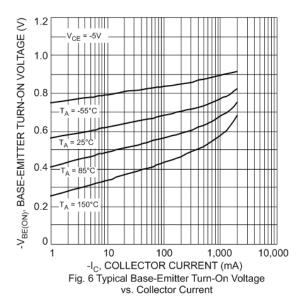
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

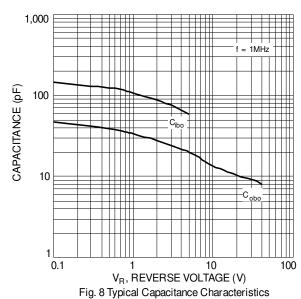


#### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









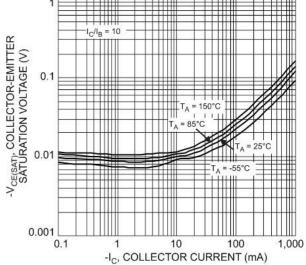


Fig. 5 Typical Collector-Emitter Saturation Voltage vs. Collector Current

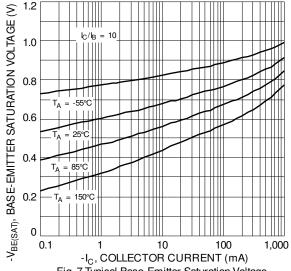
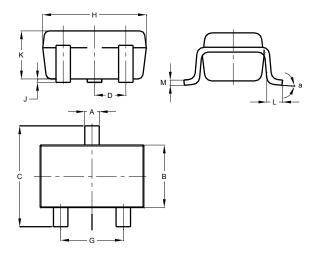


Fig. 7 Typical Base-Emitter Saturation Voltage vs. Collector Current



## **Package Outline Dimensions**

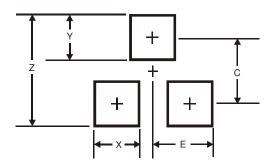
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	0.	.650 BS	C			
F	0.375	0.475	0.425			
G	1.20	1.40	1.30			
Н	1.80	2.20	2.15			
J	0.00	0.10	0.05			
K	0.90	1.00	0.95			
L	0.25	0.40	0.30			
М	0.10	0.18	0.11			
а	8°C					
All I	All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	SOT323
Z	2.8
Х	0.7
Υ	0.9
С	1.9
Е	1.0



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